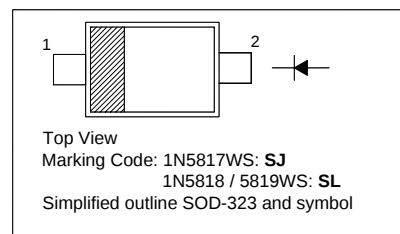


1 A Surface Mount Schottky Barrier Diode

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage B5817WS B5818WS B5819WS	V_R	20 30 40	V
Average Forward Rectified Current	$I_{F(AV)}$	1	A
Non-Repetitive Peak Forward Surge Current ($t = 8.3\text{ ms}$)	I_{FSM}	9	A
Power Dissipation	P_{tot}	450	mW
Operating Temperature Range	T_j	- 55 to + 125	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 125	$^{\circ}\text{C}$

Characteristics at $T_a = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 1\text{ mA}$ B5817WS B5818WS B5819WS	$V_{(BR)R}$	20 30 40	- - -	V
Forward Voltage at $I_F = 1\text{ A}$ B5817WS B5818WS B5819WS at $I_F = 3\text{ A}$ B5817WS B5818WS B5819WS	V_F	- - - - - -	0.45 0.55 0.6 0.75 0.875 0.9	V
Reverse Voltage Leakage Current at $V_R = 20\text{ V}$ at $V_R = 30\text{ V}$ at $V_R = 40\text{ V}$ B5817WS B5818WS B5819WS	I_R	- - -	1 1 1	mA
Total Capacitance at $V_R = 4\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	-	120	pF

1 A Surface Mount Schottky Barrier Diode

Fig. 1 - Forward Current Derating Curve

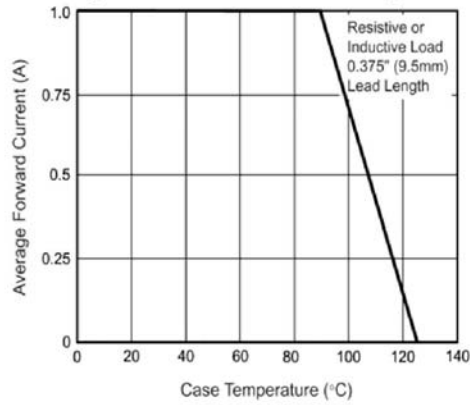


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

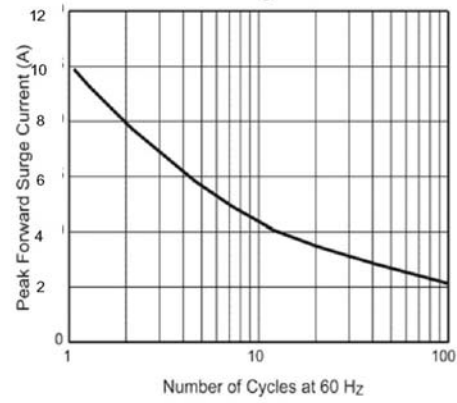


Fig. 3 - Typical Instantaneous Forward Characteristics

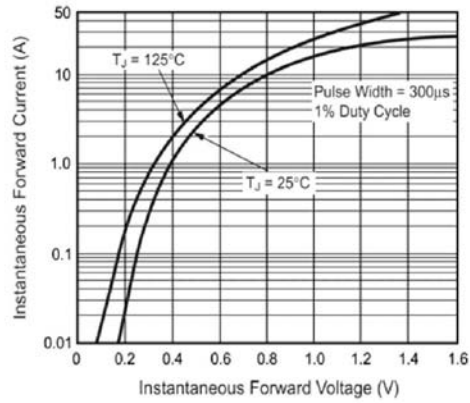


Fig. 4 - Typical Reverse Characteristics

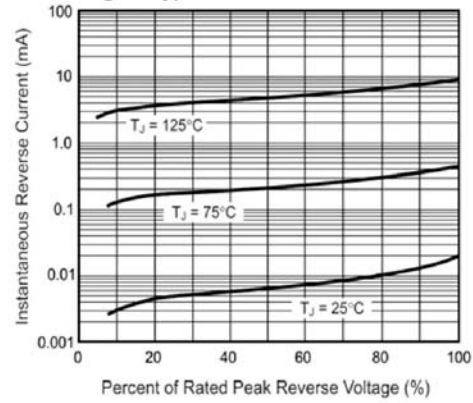


Fig. 5 - Typical Junction Capacitance

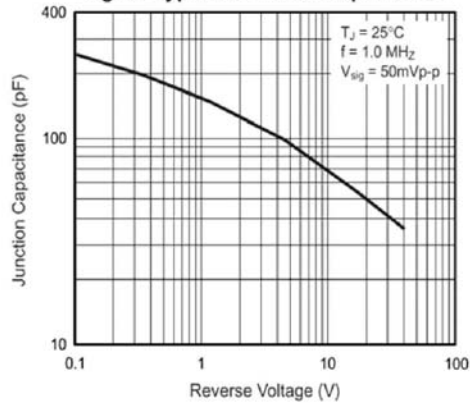
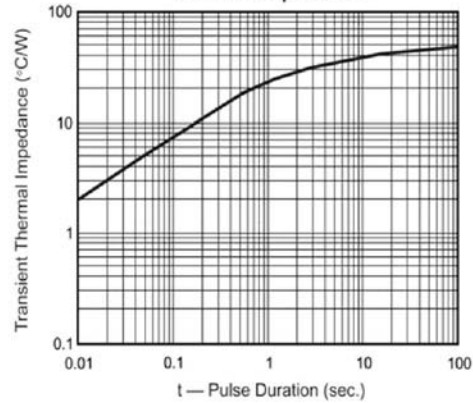


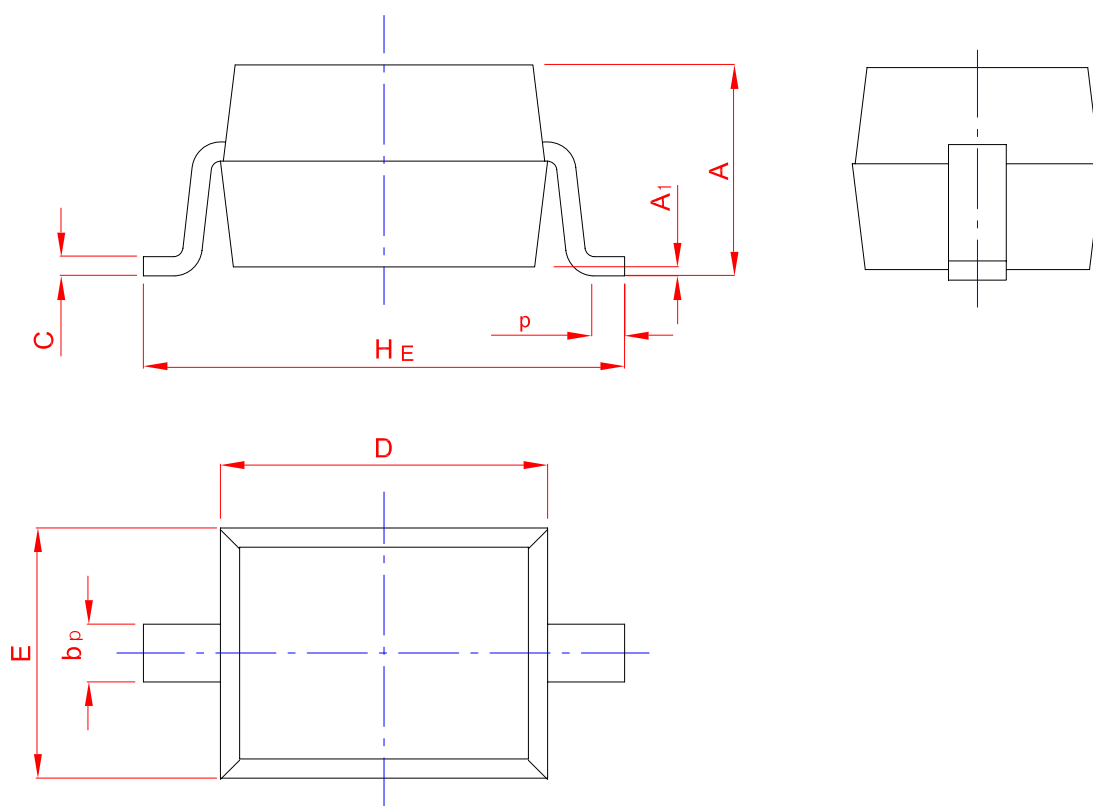
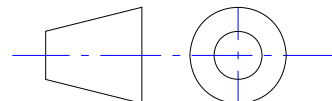
Fig. 6 - Typical Transient Thermal Impedance



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b _p	C	D	E	H _E	A ₁	L _p
mm	1.20 0.90	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20